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                 Web Page URLs for STN Seminar Schedule - N. America
NEWS 1
                "Ask CAS" for self-help around the clock
NEWS 2 Apr 08
NEWS 3 Apr 09 BEILSTEIN: Reload and Implementation of a New Subject Area
NEWS 4 Apr 09 ZDB will be removed from STN
NEWS 5 Apr 19 US Patent Applications available in IFICDB, IFIPAT, and IFIUDB
NEWS 6 Apr 22 Records from IP.com available in CAPLUS, HCAPLUS, and ZCAPLUS
NEWS 7 Apr 22 BIOSIS Gene Names now available in TOXCENTER
NEWS 8 Apr 22 Federal Research in Progress (FEDRIP) now available
NEWS 9 Jun 03 New e-mail delivery for search results now available
NEWS 10 Jun 10 MEDLINE Reload
NEWS 10 Jun 10 PCTFULL has been reloaded
NEWS 12 Jul 02 FOREGE no longer contains STANDARDS file segment
NEWS 13 Jul 22 USAN to be reloaded July 28, 2002;
                 saved answer sets no longer valid
NEWS 14 Jul 29 Enhanced polymer searching in REGISTRY
NEWS 15 Jul 30 NETFIRST to be removed from STN
NEWS 16 Aug 08 CANCERLIT reload
NEWS 17 Aug 08 PHARMAMarketLetter(PHARMAML) - new on STN
NEWS 18 Aug 08 NTIS has been reloaded and enhanced
NEWS 19 Aug 19 Aquatic Toxicity Information Retrieval (AQUIRE)
                 now available on STN
                IFIPAT, IFICDB, and IFIUDB have been reloaded
NEWS 20 Aug 19
NEWS 21 Aug 19
                The MEDLINE file segment of TOXCENTER has been reloaded
NEWS 22 Aug 26 Sequence searching in REGISTRY enhanced
                JAPIO has been reloaded and enhanced
NEWS 23 Sep 03
NEWS 24 Sep 16 Experimental properties added to the REGISTRY file
NEWS 25 Sep 16 Indexing added to some pre-1967 records in CA/CAPLUS
NEWS 26 Sep 16 CA Section Thesaurus available in CAPLUS and CA
NEWS 27 Oct 01 CASREACT Enriched with Reactions from 1907 to 1985
NEWS 28 Oct 21 EVENTLINE has been reloaded
NEWS 29 Oct 24 BEILSTEIN adds new search fields
NEWS 30 Oct 24 Nutraceuticals International (NUTRACEUT) now available on STN
NEWS 31 Oct 25 MEDLINE SDI run of October 8, 2002
NEWS 32 Nov 18 DKILIT has been renamed APOLLIT
NEWS 33 Nov 25 More calculated properties added to REGISTRY
NEWS 34 Dec 02 TIBKAT will be removed from STN
NEWS 35 Dec 04 CSA files on STN
NEWS 36 Dec 17 PCTFULL now covers WP/PCT Applications from 1978 to date
NEWS 37 Dec 17
                TOXCENTER enhanced with additional content
NEWS 38 Dec 17 Adis Clinical Trials Insight now available on STN
             October 14 CURRENT WINDOWS VERSION IS V6.01,
NEWS EXPRESS
              CURRENT MACINTOSH VERSION IS V6.0a(ENG) AND V6.0Ja(JP),
              AND CURRENT DISCOVER FILE IS DATED 01 OCTOBER 2002
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              Direct Dial and Telecommunication Network Access to STN
NEWS PHONE
              CAS World Wide Web Site (general information)
NEWS WWW
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FILE LAST UPDATED: 16 DEC 2002 <20021216/UP>
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E1	14391	BT1 S	URFACE TREATMENT/CT
E2	20865	>	ETCHING/CT
		DA	JANUARY 1969
E3	1612	NT1	DISLOCATION ETCHING/CT
E4	545	NT1	LASER BEAM ETCHING/CT
E5	15795	NT1	SPUTTER ETCHING/CT
E6	17564	RT	CORROSION/CT
E7	16575	RT	CRYSTAL DEFECTS/CT
E8	584	RT	CRYSTALS/CT
E9	3770	RT	LASER ABLATION/CT
E10	4714	RT	METALLOGRAPHY/CT
E11	8112	RT	MICROMACHINING/CT
E12	9770	RT	PRINTED CIRCUITS/CT
E13	2493	RT	PRINTING/CT
E14	14719	RT	SEMICONDUCTOR TECHNOLOGY/CT
E15	19002	CC	A6170J/CT
E16	15557	CC	A8160/CT
E17	14397	CC	B0170G/CT
E18	164	CC	B2200/CT
E19	39869	CC	B2550E/CT
E20	6290	CC	B2575F/CT
E21	1612	KT	DISLOCATION ETCHING/CT
E22	0	KT	FIB ETCHING/CT
E23	0	KT	FOCUSED ION BEAM ETCHING/CT
E24	0	KT	ION ETCHING/CT
E25	545	KT	LASER BEAM ETCHING/CT
E26	0	KT	PLASMA ETCHING/CT
E27	0	KT	REACTIVE ION ETCHING/CT
E28	0	KT	REACTIVE SPUTTER ETCHING/CT
E29	15795	KT	SPUTTER ETCHING/CT
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<sup>=&</sup>gt; ozone

L1 11332 OZONE

<sup>=&</sup>gt; water

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199298 WATER
L2
=> adsorption or adsorbed
         43433 ADSORPTION
         34682 ADSORBED
         62998 ADSORPTION OR ADSORBED
L3
=> 11 and 12 and 13
            26 L1 AND L2 AND L3
T.4
=> d 1-26
    ANSWER 1 OF 26 INSPEC COPYRIGHT 2002 IEE
T.4
Full Text
                              DN B2002-08-8695-001
     2002:7305707 INSPEC
AN
     Mechanism-analysis and simulation of the storage and removal of ozone to
TI
     level electric power loads.
     Murai, A. (Kansai Electric Power Co., Japan); Tahara, N.; Nakajima, T.
ΑU
SO
     Transactions of the Institute of Electrical Engineers of Japan, Part D
     (March 2002) vol.122-D, no.3, p.223-34. 23 refs.
     Published by: Inst. Electr. Eng. Japan
     CODEN: DGRDE5 ISSN: 0913-6339
     SICI: 0913-6339(200203)122D:3L.223:MASS;1-Y
DT
     Journal
    Practical
TC
CY
     Japan
ĽΑ
     Japanese
    ANSWER 2 OF 26 INSPEC COPYRIGHT 2002 IEE
L4
Full Text
AN
     2002:7304973 INSPEC
                              DN A2002-15-2875-012
TI
     Developmental study of dry decontamination for tritiated wastes.
     Itoh, T.; Ueda, S.; Tatenuma, K. (Kaken Co. Ltd., Ibaraki, Japan);
ΑU
     Torikai, Y.; Matsuyama, M.; Watanabe, K.
     Fusion Science and Technology (May 2002) vol.41, no.3, pt.2, p.741-5. 5
SO
     refs.
     Published by: ANS
     CODEN: FUSTE8 ISSN: 1536-1055
     SICI: 1536-1055(200205)41:3:2L.741:DSDT;1-0
     Conference: Sixth International Conference on Tritium Science and
     Technology. Tsukuba, Japan, 12-16 Nov 2001
DT
     Conference Article; Journal
TC
    Experimental
CY
    United States
LA
    English
    ANSWER 3 OF 26 INSPEC COPYRIGHT 2002 IEE
L4
Full Text
AN
     2002:7261271 INSPEC
                              DN A2002-12-5275-010
     Effects of electrode patterns on a coplanar discharge ozonizer.
TI
ΑU
    Okita, Y.; Noguchi, M.; Murata, T. (Toshiba Corp., Kawasaki, Japan)
     25th ICPIG. International Conference on Phenomena in Ionized Gases
SO
     Editor(s): Goto, T.
     Nagoya, Japan: Nagoya Univ, 2001. p.29-30 vol.4 of 4 vol.(371+273+375+365)
     pp. 3 refs.
     Conference: Nagoya, Japan, 17-22 July 2001
     Sponsor(s): IUPAP; Japan Soc. Appl. Phys.; Phys. Soc. Japan; Inst. Electr.
     Eng. Japan; et al
     ISBN: 4-9900915-0-7
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DT

Conference Article

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TC
     Practical; Experimental
CY
     Japan
LΑ
     English
     ANSWER 4 OF 26 INSPEC COPYRIGHT 2002 IEE
L4
                              DN A2002-04-8265-001
     2002:7140123 INSPEC
     Photoreactivity on a water ice surface: cyanoacetylene (HC3N) reaction
     with atomic oxygen issued from the photodissociation of ozone (03) at
     Borget, F.; Chiavassa, T. (CNRS, Univ. de Provence, Marseille, France);
AU
     Aycard, J.-P.
     Chemical Physics Letters (16 Nov. 2001) vol.348, no.5-6, p.425-32. 35
SO
     Doc. No.: S0009-2614(01)01138-1
     Published by: Elsevier
     Price: CCCC 0009-2614/01/$20.00
     CODEN: CHPLBC ISSN: 0009-2614
     SICI: 0009-2614(20011116)348:5/6L.425:PWSC;1-#
    Journal
DT
TC
    Experimental
CY Netherlands
LA English
T.4
    ANSWER 5 OF 26 INSPEC COPYRIGHT 2002 IEE
Full Text
     2001:7099545 INSPEC
                            DN A2002-01-3640-004
AN
     Equilibrium structures of the N = 64 water cluster in the presence of
ΤI
     external electric fields.
     Shevkunova, S.V. (Phys. & Mech. Dept., St. Petersburg State Tech. Univ.,
ΑU
     Russia); Vegiri, A.
     THEOCHEM (16 Nov. 2001) vol.574, p.27-38. 53 refs.
SO
     Doc. No.: S0166-1280(00)00830-7
     Published by: Elsevier
     Price: CCCC 0166-1280/01/$20.00
     CODEN: THEODJ ISSN: 0166-1280
     SICI: 0166-1280(20011116)574L.27:ESWC;1-7
DT
    Journal
TC
    Theoretical
CY
    Netherlands
LΑ
   English
    ANSWER 6 OF 26 INSPEC COPYRIGHT 2002 IEE
L4
Full Text
     2001:6855500 INSPEC
                             DN A2001-07-7865H-008
TI
    Optical properties of nanodiamond layers.
ΑU
    Aleksenskii, A.E.; Osipov, V.Yu.; Vul, A.Ya.; Ber, B.Ya.; Smirnov, A.B.;
    Melekhin, V.G. (A.F. Ioffe Physicotech. Inst., Acad. of Sci., St.
    Petersburg, Russia); Adriaenssens, G.J.; Iakoubovskii, K.
SO
    Physics of The Solid State (Jan. 2001) vol.43, no.1, p.145-50. 24 refs.
     Published by: MAIK Nauka
    Price: CCCC 1063-7834/2001/4301-0145$21.00
    CODEN: PSOSED ISSN: 1063-7834
    SICI (Trl): 1063-7834(200101)43:1L.145:OPNL;1-V
    Translation of: Fizika Tverdogo Tela (Jan. 2001) vol.43, no.1, p.140-5. 24
    CODEN: FTVTAC ISSN: 0367-3294
    SICI: 0367-3294 (200101) 43:1L.140;1-B
DT
    Journal; Translation Abstracted
TC
    Experimental
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STN Columbus
     Russian Federation; Russian Federation
CY
LΑ
     English
     ANSWER 7 OF 26 INSPEC COPYRIGHT 2002 IEE
L4
Full Text
     2000:6730246 INSPEC DN A2000-22-3320E-012
NΑ
     Infrared spectroscopy of neat solid ozone and that of ozone in
TI
     interaction with amorphous and crystalline water ice.
     Chaabouni, H.; Schriver-Mazznoli, L.; Schriver, A. (Lab. de Phys.
ΑU
     Moleculaire et Atmos., Univ. Pierre et Marie Curie, Paris, France)
     Journal of Physical Chemistry A (3 Aug. 2000) vol.104, no.30, p.6962-9. 44
SO
     refs.
     Published by: ACS
     Price: CCCC 1089-5639/2000/$19.00
     CODEN: JPCAFH ISSN: 1089-5639
     SICI: 1089-5639(20000803)104:30L.6962:ISNS;1-U
DT
     Journal
TC
     Experimental
CY
    United States
LΑ
     English
    ANSWER 8 OF 26 INSPEC COPYRIGHT 2002 IEE
L4
Full Text
     2000:6603594 INSPEC
                             DN A2000-13-3480G-006
AN
    Mechanism for giant Cl- and F- enhancements in electron-induced
ΤI
     dissociation of CF2Cl2 coadsorbed with water or ammonia ices.
     Lu, Q.-B.; Madey, T.E. (Dept. of Phys. & Astron., Rutgers Univ.,
ΑU
     Piscataway, NJ, USA)
     Surface Science (20 April 2000) vol.451, no.1-3, p.238-43. 21 refs.
SO
     Doc. No.: S0039-6028(00)00037-6
     Published by: Elsevier
     Price: CCCC 0039-6028/2000/$20.00
     CODEN: SUSCAS ISSN: 0039-6028
     SICI: 0039-6028(20000420)451:1/3L.238:MGEE;1-T
     Conference: DIET-8. Eighth International Workshop on Desorption Induced by
     Electronic Transitions. San Alfonso, NJ, USA, 27 Sept-1 Oct 1999
DT
    Conference Article; Journal
TC
    Experimental
CY
    Netherlands
LA
    English
    ANSWER 9 OF 26 INSPEC COPYRIGHT 2002 IEE
Full Text
     1999:6334163 INSPEC
                             DN A1999-19-3480G-002
AN
TI
    Giant enhancement of electron-induced dissociation of chlorofluorocarbons
     coadsorbed with water or ammonia ices: Implications for atmospheric
    ozone depletion.
    Lu, Q.-B.; Madey, T.E. (Lab. for Surface Modification & Dept. of Phys. &
ΑU
    Astron., Rutgers Univ., Piscataway, NJ, USA)
    Journal of Chemical Physics (15 Aug. 1999) vol.111, no.7, p.2861-4. 35
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    Doc. No.: S0021-9606(99)01931-5
    Published by: AIP
    Price: CCCC 0021-9606/99/111(7)/2861(4)/$15.00
    CODEN: JCPSA6 ISSN: 0021-9606
    SICI: 0021-9606(19990815)111:7L.2861:GEEI;1-V
DT
    Journal
TC
    Experimental
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United States LΑ English

CY

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ANSWER 10 OF 26 INSPEC COPYRIGHT 2002 IEE
L4
Full Text
    1999:6123482 INSPEC DN A1999-03-6860-020
AN
    Moisture instability of borophosphosilicate glass and the effects of
     thermal treatment.
    Dyer, T.W. (Semicond. Syst., Rockwell Int. Corp., Newport Beach, CA, USA)
ΑU
    Journal of the Electrochemical Society (Nov. 1998) vol.145, no.11,
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    p.3950-6. 16 refs.
    Published by: Electrochem. Soc
     Price: CCCC 0013-4651/98/$7.00
     CODEN: JESOAN ISSN: 0013-4651
     SICI: 0013-4651(199811)145:11L.3950:MIBG;1-H
DT
    Journal
    Experimental
TC
    United States
CY
LΑ
    English
    ANSWER 11 OF 26 INSPEC COPYRIGHT 2002 IEE
L4
Full Text
                            DN A9815-6845-021
AN
     1998:5955260 INSPEC
    HOCl adsorption on ice surfaces.
ΤI
     Robinson Brown, A.; Doren, D.J. (Dept. of Chem. & Biochem., Delaware
ΑU
     Univ., Newark, DE, USA)
     Journal of Physical Chemistry B (7 Aug. 1997) vol.101, no.32, p.6308-12.
SO
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     Doc. No.: S1089-5647(96)03245-2
     Published by: ACS
     Price: CCCC 1089-5647/97/$14.00
     CODEN: JPCBFK ISSN: 1089-5647
     SICI: 1089-5647(19970807)101:32L.6308:HAS;1-M
     Conference: Physics and Chemistry of Ice 1996. Hanover, NH, USA, 27-31 Aug
    Conference Article; Journal
DT
    Theoretical
TC
    United States
CY
LΑ
    English
    ANSWER 12 OF 26 INSPEC COPYRIGHT 2002 IEE
L4
Full Text
     1998:5812704 INSPEC
                             DN A9805-9220-002
AN
     Vertical profiles of bromoform in snow, sea ice, and seawater in the
ΤI
     Canadian Arctic.
     Sturges, W.T. (Sch. of Environ. Sci., East Anglia Univ., Norwich, UK);
ΑU
     Cota, G.F.; Buckley, P.T.
     Journal of Geophysical Research (15 Nov. 1997) vol.102, no.C11,
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     p.25073-83. 44 refs.
     Published by: American Geophys. Union
     Price: CCCC 0148-0227/97/97JC-01860$09.00
     CODEN: JGREA2 ISSN: 0148-0227
     SICI: 0148-0227(19971115)102:C11L.25073:VPBS;1-S
DT
     Journal
TC
     Experimental
CY
     United States
LA
    English
     ANSWER 13 OF 26 INSPEC COPYRIGHT 2002 FIZ KARLSRUHE
L4
Full Text
                              DN A9801-8265-002
     1997:5755365 INSPEC
AN
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Sheng, E.; Sutherland, I.; Bradley, R.H.; Freakley, P.K. (Loughborough
ΑU
     Univ. of Technol., UK)
     Materials Chemistry and Physics (Aug. 1997) vol.50, no.1, p.25-30. 11
SO
     Published by: Elsevier
     Price: CCCC 0254-0584/97/$17.00
     CODEN: MCHPDR ISSN: 0254-0584
     SICI: 0254-0584(199708)50:1L.25:HICS;1-0
     Journal
TTC
TC
     Experimental
     Switzerland
CY
LΑ
     English
     ANSWER 14 OF 26 INSPEC COPYRIGHT 2002 IEE
L4
Full Text
     1997:5646473 INSPEC
                              DN A9717-9260-088
AN
     The reaction of ClONO2 with HCl on aluminum oxide.
TΤ
ΑU
     Molina, M.J.; Molina, L.T.; Renyi Zhang; Meads, R.F.; Spencer, D.D. (Dept.
     of Earth Atmos. & Planetary Sci., MIT, Cambridge, MA, USA)
     Geophysical Research Letters (1 July 1997) vol.24, no.13, p.1619-22. 33
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     CODEN: GPRLAJ ISSN: 0094-8276
     SICI: 0094-8276(19970701)24:13L.1619:RCWA;1-I
DT
     Journal
ТÇ
     Experimental
     United States
CY
LА
     English
     ANSWER 15 OF 26 INSPEC COPYRIGHT 2002 FIZ KARLSRUHE
L4
Full Text
     1997:5645860 INSPEC
                              DN A9717-8670G-006
ΑN
     XPS, SIMS and SNMS applied to a combined analysis of aerosol particles
TI
     from a region of considerable air pollution in the upper Rhine valley.
ΑU
     Faude, F.; Goschnick, J. (Inst. fur Instrum. Anal., Forschungszentrum
     Karlsruhe GmbH Tech. und Umwelt, Germany)
     Fresenius' Journal of Analytical Chemistry (May 1997) vol.358, no.1-2,
     p.67-72. 15 refs.
     Published by: Springer-Verlag
     CODEN: FJACES ISSN: 0937-0633
     SICI: 0937-0633(199705)358:1/2L.67:SSAC;1-W
     Conference: 9th Applied Surface Analysis Workshop (AOFA 9). Aachen,
     Germany, 24-27 June 1996
DΤ
     Conference Article; Journal
TC
     Experimental
CY
     Germany, Federal Republic of
LΑ
     English
     ANSWER 16 OF 26 INSPEC COPYRIGHT 2002 IEE
1.4
Full Text
     1997:5639119 INSPEC
                              DN A9717-7960-005
     X-ray photoemission spectroscopy study of UV/ozone oxidation of Au under
     ultrahigh vacuum conditions.
ΑU
     Krozer, A.; Rodahl, M. (Dept. of Appl. Phys., Chalmers Univ. of Technol.,
     Goteborg, Sweden)
SO
     Journal of Vacuum Science & Technology A (Vacuum, Surfaces, and Films)
     (May-June 1997) vol.15, no.3, pt.2, p.1704-9. 17 refs.
     Doc. No.: S0734-2101(97)59603-5
     Published by: AIP for American Vacuum Soc
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Price: CCCC 0734-2101/97/15(3)/1704/6/$10.00
     CODEN: JVTAD6 ISSN: 0734-2101
     SICI: 0734-2101(199705/06)15:3:2L.1704:PSSO;1-6
     Conference: 43rd National Symposium of the American Vacuum Society.
     Philadelphia, PA, USA, 14-18 Oct 1996
     Conference Article; Journal
DT
TC
     Experimental
CY
     United States
LA
     English
     ANSWER 17 OF 26 INSPEC COPYRIGHT 2002 IEE
L4
Full Text
     1996:5191703 INSPEC
                              DN A9606-9260-018
ΤI
     Uptake of HBr on ice at polar atmospheric conditions.
     Chu, L.T.; Heron, J.W. (NYS Health Dept., Wadsworth Center, Albany, NY,
ΑU
     USA)
     Geophysical Research Letters (1 Dec. 1995) vol.22, no.23, p.3211-14. 23
SO
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     Published by: American Geophys. Union
     Price: CCCC 0094-8276/95/95GL-03290$03.00
     CODEN: GPRLAJ ISSN: 0094-8276
     SICI: 0094-8276(19951201)22:23L.3211:UPAC;1-4
DT
     Journal
TC
     Experimental
CY
     United States
LΑ
     English
     ANSWER 18 OF 26 INSPEC COPYRIGHT 2002 IEE
L4
Full Text
                              DN A9602-8240-002
AN
     1995:5128586 INSPEC
     Sulfuric acid monohydrate: formation and heterogeneous chemistry in the
TI
     stratosphere.
     Zhang, R.; Leu, M.-T.; Keyser, L.F. (Jet Propulsion Lab., California Inst.
ΑU
     of Technol., Pasadena, CA, USA)
SO
     Journal of Geophysical Research (20 Sept. 1995) vol.100, no.D9,
     p.18845-54. 43 refs.
     Price: CCCC 0148-0227/95/95JD-01876$05.00
     CODEN: JGREA2 ISSN: 0148-0227
DT
     Journal
TC
    Experimental
    United States
CY
LΑ
    English
L4
    ANSWER 19 OF 26 INSPEC COPYRIGHT 2002 IEE
Full Text
                              DN A9519-8160B-001
AN
     1995:5034436 INSPEC
     Removing sulfur from gold using ultraviolet/ozone cleaning.
ΤI
     Worley, C.G.; Linton, R.W. (Dept. of Chem., North Carolina Univ., Chapel
ΑU
     Hill, NC, USA)
     Journal of Vacuum Science & Technology A (Vacuum, Surfaces, and Films)
SO
     (July-Aug. 1995) vol.13, no.4, p.2281-4. 13 refs.
     Price: CCCC 0734-2101/95/13(4)/2281/4/$6.00
    CODEN: JVTAD6 ISSN: 0734-2101
DT
    Journal
TC
    Experimental
    United States
CY
LA
    English
L4
    ANSWER 20 OF 26 INSPEC COPYRIGHT 2002 FIZ KARLSRUHE
Full Text
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- STN Columbus DN A9517-9630G-005 1995:5017258 INSPEC ANPhotochemistry and stability of the atmosphere of Mars. ΤI Atreya, S.K.; Gu, Z.G. (Dept. of Atmos., Oceanic & Space Sci., Michigan ΑU Univ., Ann Arbor, MI, USA) Advances in Space Research (1995) vol.16, no.6, p.57-68. 28 refs. SO Price: CCCC 0273-1177/95/\$9.50+0.00 CODEN: ASRSDW ISSN: 0273-1177 Conference: Atmospheres of Venus and Mars. C3.1 Meeting of COSPAR Scientific Commission C which was held during the Thirtieth COSPAR Scientific Assembly. Hamburg, Germany, 11-21 July 1994 Conference Article; Journal DTExperimental TC CY United Kingdom LΑ English ANSWER 21 OF 26 INSPEC COPYRIGHT 2002 IEE L4Full Text DN B9406-0100-125 1994:4673480 INSPEC 1994 Semiconductor Pure Water and Chemicals Conference Proceedings. AU Editor(s): Balazs, M.K. Sunnyvale, CA, USA: Balazs Anal. Lab, 1994. ii+288 pp. SO Conference: San Jose, CA, USA, 8-10 March 1994 Conference Proceedings DT CY United States English LΑ ANSWER 22 OF 26 INSPEC COPYRIGHT 2002 IEE T.4 Full Text DN A9311-8160C-022; B9306-2550E-038 1993:4397022 INSPEC AN Native oxide growth and organic impurity removal on Si surface with TI ozone-injected ultrapure water. Ohmi, T.; Isagawa, T.; Kogure, M.; Imaoka, T. (Dept. of Electron., Tohoku AU Univ., Sendai, Japan) Journal of the Electrochemical Society (March 1993) vol.140, no.3, SO p.804-10. 17 refs. CODEN: JESOAN ISSN: 0013-4651 Journal DTTC Experimental United States CY LA English ANSWER 23 OF 26 INSPEC COPYRIGHT 2002 IEE L4Full Text DN B9209-2550G-019 1992:4211191 INSPEC AN Residual-surfactant-free photoresist development process. TIShimada, H.; Onodera, M.; Shimomura, S.; Hirose, K.; Ohmi, T. (Dept. of ΑU Electron., Tohoku Univ., Sendai, Japan) Journal of the Electrochemical Society (June 1992) vol.139, no.6, SO p.1721-30. 15 refs. CODEN: JESOAN ISSN: 0013-4651 DT Journal TCPractical; Experimental CY United States LΑ English L4ANSWER 24 OF 26 INSPEC COPYRIGHT 2002 IEE
- Full Text
- AN 1987:2859146 INSPEC DN A87054089
- Reactions of chlorine nitrate with HCl and H2O. TI
- Hatakeyama, S.; Leu, M.-T. (Jet Propulsion Lab., California Inst. of ΑU

- STN Columbus Technol., Pasadena, CA, USA) Geophysical Research Letters (Nov. 1986) vol.13, no.12, p.1343-6. 13 refs. SO Price: CCCC 0094-8276/86/006L-6298\$03.00 CODEN: GPRLAJ ISSN: 0094-8276 Journal DTExperimental TC CY United States LΑ English ANSWER 25 OF 26 INSPEC COPYRIGHT 2002 IEE L4Full Text AN 1976:990489 INSPEC DN A76094470 The absorption of solar radiation in model atmospheres. TI Kerschgens, M.; Raschke, E.; Reuter, U. (Inst. fur Geophys. und ΑU Meteorologie, Univ. zu Koln, Koln, West Germany) Contributions to Atmospheric Physics (1976) vol.49, no.2, p.81-97. 34 refs.
- CODEN: BPYAAY ISSN: 0005-8173
- DT Journal
- TC Theoretical
- CY Germany, Federal Republic of
- LA English
- L4 ANSWER 26 OF 26 INSPEC COPYRIGHT 2002 IEE

# Full Text

- AN 1974:681675 INSPEC DN A74067112; B74034073
- TI Surface cleaning by ultraviolet radiation.
- AU Sowell, R.R.; Cuthrell, R.E.; Mattox, D.M.; Bland, R.D. (Sandia Labs., Albuquerque, NM, USA)
- SO Journal of Vacuum Science and Technology (Jan.-Feb. 1974) vol.11, no.1, p.474-5. 6 refs.
  CODEN: JVSTAL ISSN: 0022-5355

Conference: 11th Conference on Microbalance Techniques. New York, NY, USA, 9-12 Oct 1973

- Sponsor(s): American Vacuum Soc
- DT Conference Article; Journal
- TC Experimental
- CY United States
- LA English

### => d 1-26 ab

- L4 ANSWER 1 OF 26 INSPEC COPYRIGHT 2002 IEE
- The authors found that it is possible to detach ozone from silica gel AB under the same temperature and same pressure conditions which silica gel adsorbed ozone. The extra energy, which is required for removing ozone, is unnecessary. Only the oxygen-purging step is required. They changed the temperature of the silica gel and measured the differences in the amount of stored ozone. The amount of adsorption became linear. It followed the expression of van't Hoff. They developed a computer program to simulate the phenomenon of the storage and removal. The results of the program demonstrated this phenomenon. The authors propose to use this method as a storage method for ozone. The ozone storage system, according to this principle, is compact and inexpensive to construct. In this system, they calculated the power consumption of a sewage plant, which processes 100,000 tons of wastewater per day. The generation ability of the ozonizer can be decreased approximately 40 percent by introducing the ozone storage unit. The storing temperature is minus 17 degrees Celsius constant, in this result the cost of storage and removal equipment

is not expensive. From these results, it is clarified that this method is effective to power load leveling.

- ANSWER 2 OF 26 INSPEC COPYRIGHT 2002 IEE L4
- With regard to tritiated contaminants, effective and simple dry decontamination method using ozone gas were proposed. By the treatment AB in ozone gas of 400 ppmv at 400 K, in the cases of stainless steel, the decontamination efficiencies of over 99% were obtained for 1 hour, and the decontamination efficiencies of aluminum were 80-86%. By the treatment of ozone gas, the quantity of the carbon atom on the surface and in inside layer were decreased, and the oxidation on the surface and in inside was proceeded, which may be assumed and expected that the recombination, release and diffusion to the surface of tritium are prevented by a rigid oxide layer generated. The ozone gas treatment is easy to use and apply in practice with a simple and safe operation. Furthermore, gas-phase decontamination technology has many advantages over conventional wet methods, in particular, its simple control processes and small secondary waste. The proposed decontamination technology has the sufficient ability and potential to simplify a decontamination operation and reduce the large volumes waste.
- L4
- ANSWER 3 OF 26 INSPEC COPYRIGHT 2002 IEE Ozone is used for sterilization, decodorization, decoloring, bleaching, and other color-related purposes. Especially, high-concentration ozone is attracting attention for large scale plants such as waste water treatments, pulp bleaching and so on. To generate high high-concentration ozone, we developed a coplanar discharge ozonizer. Coplanar discharge occurs between many pairs of electrode on a same plane of glass substrate. Since this method cools the rear side of substrate in the same manner as a conventional surface discharge method, it can efficiently cool gases formed on the surface of the electrodes. Moreover, since a coplanar discharge method can be limited to a narrow area adjacent to the electrode surface, a high electric field is formed easily. We examined electrode patterns and generation of high-concentration ozone and their relation to electric fields. As feed gas, high purity oxygen gas from cylinder or liquid oxygen, or low purity oxygen (O2/N2/Ar) from a pressure swing adsorption (PSA) gas generator was used to generate ozone. We report mainly the relationship between electrode pattern and ozone synthesis and the effects of the addition of gases in this paper.
- ANSWER 4 OF 26 INSPEC COPYRIGHT 2002 IEE L4AB
  - Cyanoacetylene (HC3N) and ozone (O3) were co-adsorbed on different sites of a water ice surface and ozone was selectively irradiated with a YAG laser at 255 nm at 20 and 60 K. Two products were observed by FTIR spectroscopy, H2O2 resulting from the direct reaction between the ice surface and atomic oxygen, and cyanoketene resulting from the reaction of cyanoacetylene and atomic oxygen. The cyanoketene was characterized in an argon matrix by laser and broad band irradiations from a co-deposition of two mixtures (O3/Ar and HC3N/Ar) at 7 K.
- ANSWER 5 OF 26 INSPEC COPYRIGHT 2002 IEE
- The structural properties of the  $N=64\ ST2$  water clusters under the L4 influence of uniform and static external electric fields are examined by AΒ means of Monte Carlo simulations. This system is taken as a model representation of an ice surface micro fragment immersed into the electric field generated by different (in sign) charges accumulated on the opposite surfaces of the fracture. Ice surface defects are considered to play an important role in the enhanced adsorption ability of vapor molecules like HCl and ClONO2. We have found that fields of the order of 107 V/cm do not affect considerably the melting transition in the cluster. However,

such a transition is not observed for fields several times stronger. Electric fields induce a significant anisotropy in the electrical characteristics of the cluster. At temperatures pertinent to stratospheric conditions, transverse to the field direction, polarization fluctuations increase considerably with the field, a fact that is related to enhanced reorientational motions of the water molecules. Field induced repulsion forces within the cluster tend to cluster elongation and even break it up.

- L4 ANSWER 6 OF 26 INSPEC COPYRIGHT 2002 IEE

  AB Thin ultradisperse diamond (UDD) layers del
- Thin ultradisperse diamond (UDD) layers deposited from a water suspension are studied by optical and X-ray photoelectron spectroscopy (XPS). The effective band gap determined by the 104-cm-1 criterion for ozone-cleaned UDD is 3.5 eV. The broad structureless photoluminescence band (380-520 nm) is associated with radiative recombination through a system of continuously distributed energy levels in the band gap of diamond nanoclusters. The optical absorption of the material at 250-1000 nm originates from absorption on the disordered nanocluster surface containing threefold-coordinated carbon. The surface of UDD clusters subjected to acid cleaning contains nitrogen-oxygen complexes adsorbed in the form of NO3\$nitrate ions. Annealing in a hydrogen atmosphere results in desorption of the nitrate ions from the cluster surface. The evolution of the oxygen (Ols) and nitrogen (Nls) lines in the XPS spectra under annealing of a UDD layer is studied comprehensively.
- L4 ANSWER 7 OF 26 INSPEC COPYRIGHT 2002 IEE
- AB The interaction of ozone with ice films under high vacuum was studied with single reflection Fourier transform infrared spectroscopy (incidence angle of 5 degrees). Both amorphous and crystalline ice were investigated. On amorphous ice which has a high density of free surface OH groups two states of ozone were observed: one which forms a hydrogen bond with the ice surface of the micropores, and a second which is attributed to a physisorbed state. Only the latter state is observed on the crystalline ice surface. When chemisorbed ozone is covered by an amorphous film, a temperature increase above 60 K leads to diffusion (with a weak yield) of ozone in the water lattice. Absorbed ozone remains in the ice bulk until sublimation of the ice film near 155 K.
- L4 ANSWER 8 OF 26 INSPEC COPYRIGHT 2002 IEE
- We have observed giant C1- and F- enhancements by factors of 102-104 in electron-induced dissociation of a fractional monolayer of CF2C12 when CF2C12 is coadsorbed with water ice or ammonia ice on a surface. The enhancement of C1- is much stronger than that of F-, and the enhancements for both ion species by NH3 coadsorbate are stronger than those by H2O. Moreover, the magnitudes of enhancement increase strongly with decreasing CF2C12 concentration. Only small negative-ion enhancements are observed for coadsorption with nonpolar CH4 molecules. It is proposed that giant negative-ion enhancements are due to dissociation of CF2C12 by capture of electrons self-trapped in polar water or ammonia molecules. This process may have far-reaching implications for the ozone-hole creation in the polar stratosphere.
- L4 ANSWER 9 OF 26 INSPEC COPYRIGHT 2002 IEE
- AB The C1- yield produced by dissociative electron attachment of a submonolayer of CF2C12 is enhanced by factors of 102 and 104 when CF2C12 is coadsorbed with water ice and ammonia ice, respectively, on a surface at 25 K. Moreover, the magnitude of C1- enhancement increases strongly with decreasing CF2C12 concentration. This enhancement is attributed to dissociation of CF2C12 by capture of electrons self-trapped in polar water or ammonia molecules. This process may be an unrecognized sink for chlorofluorocarbons in the atmosphere. C1- ions produced may be directly

or indirectly converted to Cl atoms, which then destroy ozone.

ANSWER 10 OF 26 INSPEC COPYRIGHT 2002 IEE L4

AR

Borophosphosilicate glass films deposited by tetraethoxysilane-ozone chemical vapor deposition are highly susceptible to atmospheric moisture absorption. Moisture diffuses into these oxides through the exposed surface and incorporates itself as surface adsorbed water, silanol, and phosphorous dihydroxide. Thermal treatments dehydrate the glass matrix by (i) driving off surface adsorbed water, (ii) causing pairs of silanol groups to react to form silicon dioxide, and (iii) causing doubly hydroxylated phosphorous atoms to form phosphorous-oxygen double bonds. The residual stress and thickness of as-deposited films change rapidly over time due to the moisture instability whereas these properties are stable in furnace densified films. Films treated under various rapid thermal processing conditions (temperatures from 700 to 900 degrees C and times from 10 to 50 s) are chemically similar to each other but have different physical properties depending on the specific conditions of the cure. The degree of chemical and physical change that takes place in these films over time also depends on the specific cure conditions. Phosphorous hydration plays an important role in these changes which correlate more strongly with the cure temperature than the cure time. For all of the cure conditions studied, the postcure film density is a consistently good predictor of the subsequent film stability.

ANSWER 11 OF 26 INSPEC COPYRIGHT 2002 IEE L4

HOCl has been implicated in the destruction of stratospheric ozone via a AΒ reaction catalyzed on ice surfaces in polar stratospheric clouds. Adsorption of HOCl on ice is a prototype of a simple ice surface reaction, and it has been the subject of several laboratory studies, making this a valuable case for testing theoretical approaches to ice surface reactions. The present paper describes a first-principles theoretical study of HOCl adsorption on ice, applying density functional theory (DFT) to cluster models of the (0001) surface of ice Ih. In the most stable binding configurations, HOCl acts as a proton donor in a hydrogen bond. The strength of HOCl binding on the surface depends not only on the hydrogen bonding interaction but also on electrostatic and many-body interactions with neighboring water molecules. The results of these DFT calculations are compared to post-Hartree-Fock calculations of the H2O-HOCl complex and to empirical potential simulations of HOCl on ice.

ANSWER 12 OF 26 INSPEC COPYRIGHT 2002 IEE T.4

Bromoform (CHBr3) was measured in vertical profiles from the snow surface AΒ through the snowpack, sea ice, and water column to the seafloor at Resolute Bay, Canada, in the spring of 1992. Elevated concentrations of bromoform were observed in both the ice and seawater at the ice-water interface, associated with bromoform emission from ice microalgae. A surprising finding was a second horizon of high bromoform concentrations in sea ice at the snow-ice interface. Chlorophyll and salinity were also elevated in this upper ice layer, although chlorophyll was much lower than in the basal ice microalgal layer. We speculate that this upper bromoform-enriched layer may have originated from scavenging of the surface water layer by frazil ice during initial ice formation in the preceding autumn. Equally unexpected was the occurrence of yet higher bromoform concentrations in snowpack immediately overlying the sea ice, declining in concentration (by about a factor of 2 or more) toward the snow surface. Snow of very recent origin, however, contained as little as 2 orders of magnitude less bromoform than the older snowpack. Possible origins for elevated bromoform in the snowpack include diffusion out of the bromoform-enriched upper ice layer and gradual concentration of

bromoform out of the atmosphere by adsorption on to ice crystals. In one scenario, photolysis of bromoform from snow is considered, which might help account for atmospheric bromine-ozone chemistry. The possible contributions from snow, sea ice, and seawater to atmospheric bromoform levels during both the winter and spring are also considered, and if is concluded that surface seawater presents the most significant reservoir for atmospheric bromoform.

- ANSWER 13 OF 26 INSPEC COPYRIGHT 2002 FIZ KARLSRUHE
- L4Immersional heats of carbon blacks into n-heptane and water have been AΒ investigated. It has been found that the dispersion component of the carbon black surface free energy ( gamma sd) calculated from heat of immersion data slightly decreases with the surface oxygen concentration, which is suggested to be caused by the partial perturbation of the graphitic structure on the carbon black surface. gamma sd was also calculated from the nitrogen adsorption data and compared with that from heat of immersion data. The heat of immersion in water increases with the carbon black surface oxygen concentration. The ozone oxidation of the carbon black has been found to improve the filled-rubber properties for a polar rubber (nitrile butadiene rubber), but to decrease the properties for a non-polar rubber (natural rubber).
- ANSWER 14 OF 26 INSPEC COPYRIGHT 2002 IEE L4
- The chlorine activation reaction ClONO2+HCl to HNO3+Cl2 was investigated AΒ in the laboratory on hydroxylated alpha -alumina surfaces under reactant partial pressure, humidity, and temperature conditions covering those which are encountered at mid-latitudes in the lower stratosphere. The measured reaction probability is gamma 0.02. This result has implications with regard to the stratospheric impact of launch vehicles utilizing solid-fuel rocket motors (SRMs), such as the Space Shuttle. The exhaust from SRMs consists of alumina particles and of HCl and other vapors. The reaction probability measured in this work suggests that the ozone depletion potential of SRMs may be higher than that predicted on the basis of the chlorine emissions alone, especially at mid-latitudes in the lower stratosphere, where catalytic chlorine activation by background sulfuric acid aerosols is very inefficient. The reaction probability on Pyrex glass was found to be similar to that on alpha -alumina. The reaction mechanism appears to be determined by the water layers adsorbed on the surface, rather than by the detailed nature of the refractory surface itself.
- ANSWER 15 OF 26 INSPEC COPYRIGHT 2002 FIZ KARLSRUHE
- L4The water acceptance of aerosol particle surfaces is a key factor for AΒ atmospheric hygiene as it initiates gravitational settling by water up-take. To examine the concurrent influences on the surface of real airborne particles concerning the deposition of hydrophobic organic material, six particle sampling campaigns were performed in polluted outdoor-air under different air conditions. The particles were examined with SNMS, SIMS, and XPS with special view of the chemical inventory of the surface region. The total elemental inventory obtained with SNMS shows carbon compounds in all particle size classes. Soot seems to govern the submicron particles while the coarse fraction contains soil dust or fly ash. Depth-resolved analysis shows organic carbon compounds to be surface-enriched and to dominate the composition of the topmost molecular layers of the particles independent of the collection time and particle sizes. However, chlorides and ammonium sulfate were also found at the surface which will always reduce the hydrophobicity of the surface caused by organic compounds. No correlation was discovered between the ozone or NO2 concentration of the air and the type and quantity of the organic surface components.

- L4 ANSWER 16 OF 26 INSPEC COPYRIGHT 2002 IEE
- AB (111) textured Au films were oxidized under UHV conditions by exposing them to UV radiation and ozone. The Au films were characterized by X-ray photoelectron spectroscopy. The gold surface becomes heterogeneous upon oxidation: approximately 0.8 monolayer (ML) of the adsorbed oxygen is present as chemisorbed species. The rest of the adsorbed oxygen forms, on the average, a few ML thick gold oxide with a stoichiometry close to Au2O3. Both the oxide and the chemisorbed oxygen disappear slowly when heated to 150 degrees C. During isothermal decomposition at 200 degrees C, the oxide is transformed to chemisorbed oxygen prior to desorption. Both the chemisorbed oxygen and the gold oxide can be removed by rinsing with water, and the surface is hydrophilic after the rinse. When contaminated gold films are exposed to UV/ozone, impurity oxides appear at higher binding energies than the binding energies of oxygen on clean gold samples. The impurity oxides are thermally much more stable than Au2O3.
- L4 ANSWER 17 OF 26 INSPEC COPYRIGHT 2002 IEE
- The uptake of HBr in water ice has been investigated in a flow reactor under polar atmospheric conditions. The HBr uptake on ice films was determined in the range of 1.1+or-0.7\*1014-7.7+or-1.1\*1016 molecules/cm2 at 188 and 195 K as HBr partial pressures varied from 3.7\*10-8 to 6.4\*10-6 Torr. This is the first report of a laboratory study at polar atmospheric conditions that shows HBr.3H2O to be formed during the uptake process. The HBr adsorption and uptake thermodynamics were also investigated. The implications of these new findings for the heterogeneous chemistry of the polar ozone depletion are briefly discussed.
- L4 ANSWER 18 OF 26 INSPEC COPYRIGHT 2002 IEE
- Investigates some thermodynamic properties (i.e., freezing/melting points) AΒ and heterogeneous chemistry of sulfuric acid monohydrate (SAM, H2SO4.H2O), using a fast flow reactor coupled to a quadrupole mass spectrometer. The freezing point observations of thin liquid sulfuric acid films show that for acid contents between 75 and 85 wt. 8 the monohydrate crystallizes readily at temperatures between 220 and 240 K on a glass substrate. Once formed, SAM can be thermodynamically stable in the H2O partial pressure range of (1-4)\*10-4 torr and in the temperature range of 220-240 K. For a constant H2O partial pressure, lowering the temperature causes SAM to melt when the temperature and water partial pressure conditions are out of its stability regime. The reaction probability measurements indicate that the hydrolysis of N2O5 is significantly suppressed owing to the formation of crystalline SAM: The reaction probability on water-rich SAM (with higher relative humidity, or RH) is of the order of 10-3 at 210 K and decreases by more than an order of magnitude for the acid-rich form (with lower RH). The hydrolysis rate of ClONO2 on water-rich SAM is even smaller, of the order of 10-4 at 195 K. These reported values on crystalline SAM are much smaller than those on liquid solutions. No enhancement of these reactions is observed in the presence of HCl vapor at the stratospheric concentrations. In addition, Brunauer, Emmett, and Teller analysis of gas adsorption isotherms and photomicrography have been performed to characterize the surface roughness and porosities of the SAM substrate. The results suggest the possible formation of SAM in some regions of the middle- or low-latitude stratosphere and, consequently, much slower heterogeneous reactions on the frozen aerosols.
- L4 ANSWER 19 OF 26 INSPEC COPYRIGHT 2002 IEE
- AB A gold surface exposed to UV light can be purged of sulfur impurities via oxidation of chemisorbed sulfur to sulfonates which can then be removed by washing with high purity water. The UV cleaning process involves UV conversion of oxygen to ozone and atomic oxygen which then transform surface species to either volatile states that desorb, or highly oxidized

molecules which are water soluble. The UV/ozone method allows one to remove old self-assembled (SA) thiol monolayers and to provide a fresh surface for aditional SA experiments. In addition, gold which has been contaminated by ambient sulfur can be cleaned by the UV protocol. Because the method only requires a UV lamp and high purity water for eliminating certain inorganics such as sulfur, the use of other chemicals required in solvent cleaning protocols is unnecessary. UV treatment is noninvasive because it only affects adsorbed surface molecules and not inert substrates such as gold. Thus surface roughening at the atomic scale which occurs with ion bombardment methods is avoided. The UV process, then, should be ideal for cleansing atomically flat gold substrates needed in scanning microscopy studies of SA monolayers.

- ANSWER 20 OF 26 INSPEC COPYRIGHT 2002 FIZ KARLSRUHE L4
- An understanding of the composition, structure, transport and AΒ photochemical processes of the present atmosphere of Mars is essential for addressing such fundamental questions as the stability, evolution and the origin of the Martian atmosphere. This paper discusses our current knowledge of the photochemistry and stability of the Martian atmosphere, with special emphasis on new models and work in progress. The atmosphere of Mars is composed mainly of CO2 (95.3% by volume), N2 (2.7%), and 40Ar (1.6%). Trace constituents, especially H2O vapor (150-200 ppm, average), CO (0.07%), O2 (0.13%), and ozone (0.03 ppm average) make up the rest. Vertical mixing, characterized by an eddy diffusion coefficient, is of the order of 106 cm2 s-1 up to 40 km, rising to 108 cm2 s-1 at the homopause (125 km). Photochemistry initiated by the solar ultraviolet dissociation of CO2 and H2O, results in the formation and distribution of the above-mentioned trace constituents. The homogeneous gas phase chemical reactions, however, do not entirely explain the stability of CO2, O2, or CO, thus necessitating the inclusion of heterogeneous adsorption as a loss mechanism for certain species, such as H2O, OH, H2O2, O or O2 on aerosols of dust or ice suspended in the Martian air.
- ANSWER 21 OF 26 INSPEC COPYRIGHT 2002 IEE
- L4The following topics were dealt with: non-ionic silica removal using AB ozone-UV treatment for semiconductor ultrapure water systems; colloidal substances in ozone-UV treatment; perfluoroelastomers gaskets and sealers in semiconductor wet processing; boron behaviour in ultrapure water manufacturing systems; organic contaminants removal from Si wafer surface; nonvolatile residue measurement of small volume solvents; metallic contaminants removal in an RCA-2 clean; deposition and removal mechanism of noble metals in wet chemical processing; noble metal contamination prevention during Si processing; ultra-pure IPA purification and recycling system; advanced processing technology for spent semiconductor; on-site blending and delivery of dilute HF to wafer cleaning and etching equipment; particles analysis in high purity hydrogen peroxide by laser counter; particle deposition control for various wafer surfaces; surface micro roughness and etch rate comparison using atomic force microscopy; and adsorption/desorption in ICP-MS.
- ANSWER 22 OF 26 INSPEC COPYRIGHT 2002 IEE L4
- To manufacture ULSI devices with high performance and reliability in large AΒ volume, further integration and miniaturization are being promoted. The key issue in realizing what the authors call 'Noise-free Manufacturing' is to keep the wafer surface ultraclean all the time. To realize the ultraclean wafer, organic impurities adsorbed on the wafer surface must be removed first before other wafer cleaning procedures. This is because native oxide and metallic impurities on the wafer cannot be removed completely in the presence of residual organic impurities on the surface. The conventional wet cleaning process is designed to have the

H2SO4/H2O2/H2O cleaning performed at the first stage to remove organic impurities on the wafer. Because the solution in this cleaning must be heated to about 130 degrees C, the chemical composition of the solution cannot be maintained at a constant level. This means that the cleaning is not perfectly controlled. The H2SO4/H2O2/H2O cleaning has another serious problem: the cleaning step produces a large volume of chemical waste that must be treated properly. They have developed a cleaning technology using ozone-injected ultrapure water. Ozone concentration in the water is 1-2 p.p.m. This process is capable of effectively removing organic contaminants from the wafer surface in a short time at room temperature. Processing waste from this process is simple. Chemical composition of the ozone-injected ultrapure water can be controlled easily.

- L4 ANSWER 23 OF 26 INSPEC COPYRIGHT 2002 IEE
- The addition of small amounts of surfactant and hydrogen peroxide (H2O2) to the developer is shown to improve the performance of the photoresist development process. Exposed photoresist areas are dissolved more uniformly, the smoothness of Si surface is maintained, and carbon contamination during the development process is prevented. Ozone (O3) treated ultrapure water rinsing at room temperature is an efficient way to remove the surfactant adsorbed on Si surface. A surfactant-added developer improves wettability on the photoresist surface, which leads to more uniform developing. The dissolution rate in the exposed photoresist is promoted and the etching rate of Si substrate is suppressed due to the effect of the additional surfactant. The only major disadvantage, due to the reaction of the surfactant in the strong alkali solution, is that the surfactant remains adsorbed on Si surface. H2O2 additions to the developer or ozone treated rinse water can remove the surfactant residues.
- L4 ANSWER 24 OF 26 INSPEC COPYRIGHT 2002 IEE
- The kinetics of the reactions of chlorine nitrate with HCl and H2O have been investigated using a static photolysis/Fourier transform infrared spectrophotometer apparatus. Upper limits for the rate constants for the homogeneous gas-phase reactions of ClONO2+HCl (1) and ClONO2+H2O (2) were estimated to be <8.4\*10-21 and <3.4\*10-21 cm3 molec-1 s-1 respectively, at 296+or-2K. The yields of HNO3 were 1.05+or-0.09 and 0.86+or-0.08, respectively. No synergistic effect between H2O and HCl was observed. The kinetic behavior of reaction (2) was well described by simple first-order kinetics while the behavior of reaction (1) was found to be well described in terms of the Langmuir adsorption isotherm. The results are of interest to stratospheric O3 studies.
- L4 ANSWER 25 OF 26 INSPEC COPYRIGHT 2002 IEE
- The absorption of solar radiation of the wave-length interval from 200 to AB 3580 nm is studied in clear, but inhomogeneously stratified model atmospheres with an iterative solution of the radiative transfer equation. The influence of ground albedo on the radiative heating in all layers is studied with a rough ocean and a bright desert surface as lower boundaries. Integral band transmission functions for water vapour, oxygen and carbon dioxide are approximated by finite series of exponentials. It is shown that the vertical profiles of radiative heating are determined in all layers up to 70 km altitude by the transmission functions of atmospheric gases from different sources and also by the accuracy of their fit with a series of exponentials. In the lower stratosphere the multiple scattering and adsorption by aerosols, CO2 and H2O may double the solar heating compared to that by ozone only. In all atmospheric layers an increase of absorption is found by an increasing surface albedo and dust content as well.

UV radiation had been used for removing photoresist films and its action AΒ attributed to depolymerization and oxidation arising from the presence of ozone. In the study reported u.v. light from commercial mercury vapour lamps (blacklights) was employed to irradiate glass (0110) and gold surfaces contaminated by adsorbed hydrocarbons. The coefficient of adhesion for Au on Au obtained by u.v. irradiation in a UhV-system at 10-4 torr O2-pressure was the same as that obtained by baking in UhV or sputter cleaning. Exposure without oxygen present gave an inferior coefficient of adhesion. Several hours of u.v. exposure in the laboratory air gave equivalent cleaning to heating to red heat. The glass coated with wax and degreased in trichloroethylene when irradiated (approximately 2 mW/cm2) for 15 h in air had a contact angle for water of zero compared with an initial value of approximately 28 degrees . The cleaning characteristics of As-received silica slides were variable but became consistent after sputter cleaning.

### => d his

(FILE 'HOME' ENTERED AT 17:35:50 ON 17 DEC 2002)

FILE 'INSPEC' ENTERED AT 17:35:59 ON 17 DEC 2002 E ETCHING + ALL/CT

L1 11332 OZONE

L2 199298 WATER

L3 62998 ADSORPTION OR ADSORBED

L4 . 26 L1 AND L2 AND L3

=> d 4,19,22,23 all

L4 ANSWER 4 OF 26 INSPEC COPYRIGHT 2002 IEE

## Full Text

AN 2002:7140123 INSPEC DN A2002-04-8265-001

TI Photoreactivity on a water ice surface: cyanoacetylene (HC3N) reaction with atomic oxygen issued from the photodissociation of ozone (O3) at 255 nm.

AU Borget, F.; Chiavassa, T. (CNRS, Univ. de Provence, Marseille, France); Aycard, J.-P.

SO Chemical Physics Letters (16 Nov. 2001) vol.348, no.5-6, p.425-32. 35 refs.

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SICI: 0009-2614(20011116)348:5/6L.425:PWSC;1-#

DT Journal

TC Experimental

CY Netherlands

LA English

Cyanoacetylene (HC3N) and ozone (O3) were co-adsorbed on different sites of a water ice surface and ozone was selectively irradiated with a YAG laser at 255 nm at 20 and 60 K. Two products were observed by FTIR spectroscopy, H2O2 resulting from the direct reaction between the ice surface and atomic oxygen, and cyanoketene resulting from the reaction of cyanoacetylene and atomic oxygen. The cyanoketene was characterized in an argon matrix by laser and broad band irradiations from a co-deposition of two mixtures (O3/Ar and HC3N/Ar) at 7 K.

CC A8265J Heterogeneous catalysis at surfaces and other surface reactions; A8280D Electromagnetic radiation spectrometry (chemical analysis); A8250F Photolysis and photodissociation by IR, UV and visible radiation

- CT **ADSORBED** LAYERS; FOURIER TRANSFORM SPECTRA; ICE; INFRARED SPECTRA; ORGANIC COMPOUNDS; **OZONE**; PHOTODISSOCIATION; SPECTROCHEMICAL ANALYSIS; SURFACE CHEMISTRY
- photoreactivity; H2O ice surface; cyanoacetylene/O reaction; photodissociation; O3; ozone; co-adsorbed species; irradiated YAG laser; FTIR spectroscopy; cyanoketene; Ar matrix; broad band irradiation; co-deposition; O3/Ar mixture; cyanoacetylene/Ar mixture; 255 nm; 60 K; 20 K; 7 K; H2O2; H2O
- CHI H2O2 bin, H2 bin, O2 bin, H bin, O bin; H2O sur, H2 sur, H sur, O sur, H2O bin, H2 bin, H bin, O bin; O3 ads, O ads, O3 el, O el
- PHP wavelength 2.55E-07 m; temperature 6.0E+01 K; temperature 2.0E+01 K; temperature 7.0E+00 K
- ET C\*H\*N; HC3N; H cp; cp; C cp; N cp; H\*O; H2O2; O cp; H2O; Ar; H; O
- L4 ANSWER 19 OF 26 INSPEC COPYRIGHT 2002 IEE

## Full Text

- AN 1995:5034436 INSPEC DN A9519-8160B-001
- TI Removing sulfur from gold using ultraviolet/ozone cleaning.
- AU Worley, C.G.; Linton, R.W. (Dept. of Chem., North Carolina Univ., Chapel Hill, NC, USA)
- SO Journal of Vacuum Science & Technology A (Vacuum, Surfaces, and Films) (July-Aug. 1995) vol.13, no.4, p.2281-4. 13 refs. Price: CCCC 0734-2101/95/13(4)/2281/4/\$6.00 CODEN: JVTAD6 ISSN: 0734-2101
- DT Journal
- TC Experimental
- CY United States
- LA English
- A gold surface exposed to UV light can be purged of sulfur impurities via AΒ oxidation of chemisorbed sulfur to sulfonates which can then be removed by washing with high purity water. The UV cleaning process involves UV conversion of oxygen to ozone and atomic oxygen which then transform surface species to either volatile states that desorb, or highly oxidized molecules which are water soluble. The UV/ozone method allows one to remove old self-assembled (SA) thiol monolayers and to provide a fresh surface for aditional SA experiments. In addition, gold which has been contaminated by ambient sulfur can be cleaned by the UV protocol. Because the method only requires a UV lamp and high purity water for eliminating certain inorganics such as sulfur, the use of other chemicals required in solvent cleaning protocols is unnecessary. UV treatment is noninvasive because it only affects adsorbed surface molecules and not inert substrates such as gold. Thus surface roughening at the atomic scale which occurs with ion bombardment methods is avoided. The UV process, then, should be ideal for cleansing atomically flat gold substrates needed in scanning microscopy studies of SA monolayers.
- CC A8160B Surface treatment and degradation of metals and alloys
- CT GOLD; SULPHUR; SURFACE CLEANING
- ST ozone cleaning; S impurities; high purity water; UV cleaning; self-assembled thiol monolayers; adsorbed surface molecules; Au; S
- CHI Au sur, Au el; S ads, S el
- ET S; Au
- L4 ANSWER 22 OF 26 INSPEC COPYRIGHT 2002 IEE

#### Full Text

- AN 1993:4397022 INSPEC DN A9311-8160C-022; B9306-2550E-038
- TI Native oxide growth and organic impurity removal on Si surface with ozone-injected ultrapure water.
- AU Ohmi, T.; Isagawa, T.; Kogure, M.; Imaoka, T. (Dept. of Electron., Tohoku Univ., Sendai, Japan)
- SO Journal of the Electrochemical Society (March 1993) vol.140, no.3,

p.804-10. 17 refs.

CODEN: JESOAN ISSN: 0013-4651

- DT Journal
- TC Experimental
- CY United States
- LA English
- To manufacture ULSI devices with high performance and reliability in large AΒ volume, further integration and miniaturization are being promoted. The key issue in realizing what the authors call 'Noise-free Manufacturing' is to keep the wafer surface ultraclean all the time. To realize the ultraclean wafer, organic impurities adsorbed on the wafer surface must be removed first before other wafer cleaning procedures. This is because native oxide and metallic impurities on the wafer cannot be removed completely in the presence of residual organic impurities on the surface. The conventional wet cleaning process is designed to have the H2SO4/H2O2/H2O cleaning performed at the first stage to remove organic impurities on the wafer. Because the solution in this cleaning must be heated to about 130 degrees C, the chemical composition of the solution cannot be maintained at a constant level. This means that the cleaning is not perfectly controlled. The H2SO4/H2O2/H2O cleaning has another serious problem: the cleaning step produces a large volume of chemical waste that must be treated properly. They have developed a cleaning technology using ozone-injected ultrapure water. Ozone concentration in the water is 1-2 p.p.m. This process is capable of effectively removing organic contaminants from the wafer surface in a short time at room temperature. Processing waste from this process is simple. Chemical composition of the ozone-injected ultrapure water can be controlled easily.
- CC A8160C Semiconductors; B2550E Surface treatment; B2520C Elemental semiconductors
- CT ELEMENTAL SEMICONDUCTORS; SILICON; SURFACE TREATMENT
- st native oxide growth; semiconductor; organic impurity removal; ozone-injected ultrapure water; ULSI devices; wafer surface ultraclean; wet cleaning; Si surface; O3-H2O; SiO2-Si
- CHI O3H2O bin, H2 bin, O3 bin, H bin, O bin; SiO2-Si int, SiO2 int, O2 int, Si int, O int, SiO2 bin, O2 bin, Si bin, O bin, Si el; Si sur, Si el
- ET Si; H\*O\*S; H2SO4; H cp; cp; S cp; O cp; H\*O; H2O2; H2O; C; O3-H2O; O\*Si; O sy 2; sy 2; Si sy 2; SiO2; Si cp; SiO2-Si; O3H2O; H; O; SiO
- L4 ANSWER 23 OF 26 INSPEC COPYRIGHT 2002 IEE

# Full Text

- AN 1992:4211191 INSPEC DN B9209-2550G-019
- TI Residual-surfactant-free photoresist development process.
- AU Shimada, H.; Onodera, M.; Shimomura, S.; Hirose, K.; Ohmi, T. (Dept. of Electron., Tohoku Univ., Sendai, Japan)
- Journal of the Electrochemical Society (June 1992) vol.139, no.6, p.1721-30. 15 refs.

  CODEN: JESOAN ISSN: 0013-4651
- DT Journal
- TC Practical; Experimental
- CY United States
- LA English
- The addition of small amounts of surfactant and hydrogen peroxide (H2O2) to the developer is shown to improve the performance of the photoresist development process. Exposed photoresist areas are dissolved more uniformly, the smoothness of Si surface is maintained, and carbon contamination during the development process is prevented. Ozone (O3) treated ultrapure water rinsing at room temperature is an efficient way to remove the surfactant adsorbed on Si surface. A surfactant-added developer improves wettability on the photoresist surface, which leads to more uniform developing. The dissolution rate in the exposed photoresist

is promoted and the etching rate of Si substrate is suppressed due to the effect of the additional surfactant. The only major disadvantage, due to the reaction of the surfactant in the strong alkali solution, is that the surfactant remains adsorbed on Si surface. H2O2 additions to the developer or ozone treated rinse water can remove the surfactant residues.

- CC B2550G Lithography
- CT PHOTORESISTS; SEMICONDUCTOR TECHNOLOGY
- ST residual surfactant free photoresist; C contamination; semiconductor device technology; development process; surfactant; performance; wettability; dissolution rate; etching rate; ozone treated rinse water; Si surface; H2O2
- CHI Si sur, Si el; H2O2 bin, H2 bin, O2 bin, H bin, O bin
- ET H\*O; H2O2; H cp; cp; O cp; Si; C; H2O; H; O